


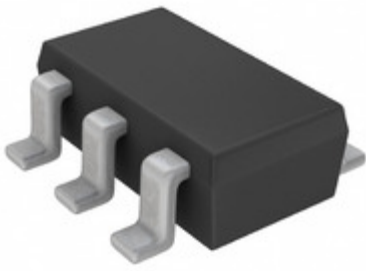










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|   | <h2 style="color: orange;">RTQ020N05TR</h2> |
| | <p>Hersteller-Teilenummer: RTQ020N05TR</p> <hr/> <p>Hersteller / Marke: LAPIS Semiconductor</p> <hr/> <p>Teil der Beschreibung: MOSFET N-CH 45V 2A TSMT6</p> <hr/> <p>Datenblätter:  RTQ020N05TR.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 21608 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p> |
|  | |
| <p>Image may be representation. See specs for product details.</p> | |

Spezifikationen

| | |
|--|---|
| Teilenummer | RTQ020N05TR |
| Hersteller | LAPIS Semiconductor |
| Beschreibung | MOSFET N-CH 45V 2A TSMT6 |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs , |
| Teilstatus | 21608 pcs Stock |
| Serie | - |
| Technologie | MOSFET (Metal Oxide) |
| Betriebstemperatur | 150 °C (TJ) |
| Befestigungsart | Surface Mount |
| Verpackung / Gehäuse | SOT-23-6 Thin, TSOT-23-6 |
| Supplier Device-Gehäuse | TSMT6 (SC-95) |
| Verlustleistung (max) | 600mW (Ta) |
| Typ FET | N-Channel |
| FET-Merkmal | - |
| Drain-Source-Spannung (Vdss) | 45V |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 2A (Ta) |
| Rds On (Max) @ Id, Vgs | 190 mOhm @ 2A, 4.5V |
| VGS (th) (Max) @ Id | 1.5V @ 1mA |
| Gate Charge (Qg) (Max) @ Vgs | 2.3nC @ 4.5V |
| Eingabekapazität (Ciss) (Max) @ Vds | 150pF @ 10V |
| Verpackung | Tape & Reel (TR) |

RTQ020N05TR ist neu im Original, Suche RTQ020N05TR Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie RTQ020N05TR LAPIS Semiconductor mit Garantie und Vertrauen. Anfrage RTQ020N05TR: Info@Y-IC.com

Sie können auch interessiert sein:

| | | | |
|---|---|--|--|
|  <p>RTQ020N05 R RTQ020N05 R</p> |  <p>RTQ020N03FRA ROHM ROHM SOT23-6</p> |  <p>RTQ020N05FRA ROHM RTQ020N05FRA ROHM</p> |  <p>RTQ020N03TR LAPIS Semiconductor MOSFET N-CH 30V 2A TSMT6</p> |
|  <p>RTQ025P02 ROHM RTQ025P02 ROHM</p> |  <p>RTQ025P02-TL ROHM RTQ025P02-TL ROHM</p> |  <p>RTQ025P02 TR ROHM RTQ025P02 TR ROHM</p> |  <p>RTQ020N05 TR ROHM RTQ020N05 TR ROHM</p> |

heiße Teile

Mehr

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|----------------|---------------|----------------|---------------------|--------------------|
| 1808AA152JAT1A | 562R5GAT22 | AK4116VN-L | D B39951-B4684-Z610 | CDRH4D28CLD-2R2NC |
| DS133833 | FSV1045V | D FZ1200R17KF6 | QGM1885C1H300JB01D | GRJ188C70J475KE11D |
| HA13460FP01-EL | HD6433827A13W | ICM7555CBA | IRL2203NLPBF | LM27964SQ-A |
| D LT1580IQ | MCC19-06IO1B | MPC82E54AE2 | PCA9548APWR | PCF85163T/1 |
| PT2332-X | RTQ020N03 | RTQ020N03TR | RTQ020N05 | RTQ020N05FRA |
| RTQ025P02 | RTQ025P02-TL | D RTQ025P02FRA | RTQ025P02TL | RTQ025P02TR |
| RTQ030P02 | D RTQ030P02TR | RTQ035N03 | RTQ035N03FRA | RTQ035N03HZG |
| RTQ035N03TR | RTQ035P02 | RTQ035P02FHA | RTQ035P02TR | RTQ040P02 |
| RTQ040P02TR | RTQ045N03 | RTQ045N03FRA | D RTQ045N03FRATR | RTQ045N03TR |
| SD800C40L | SKB60/012 | T1078F200TCB | TLV2262AIDRG4 | V300C8M100BN |

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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